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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/035,444	01/04/2002	Fumikazu Yamaki	011796	3015
23850 759	08/14/2002			
ARMSTRONG,WESTERMAN & HATTORI, LLP 1725 K STREET, NW. SUITE 1000			EXAMINER	
			TRAN, TAN N	
WASHINGTON, DC 20006			ART UNIT	PAPER NUMBER
			2826	5
			DATE MAILED: 08/14/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)					
Office Action Summary								
		10/035,444	YAMAKI ET AL.					
	Onice Action Summary	Examiner	Art Unit					
	The MAILING DATE of this communication ann	TAN N TRAN	et with the correspondence address					
Period	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
THE - Ex aft - If t - If r - Fa - An	HORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. E MAILING DATE OF THIS COMMUNICATION. The ser SIX (6) MONTHS from the mailing date of this communication. The period for reply specified above is less than thirty (30) days, a reply NO period for reply is specified above, the maximum statutory period we liture to reply within the set or extended period for reply will, by statute, by reply received by the Office later than three months after the mailing made patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, r within the statutory minimum will apply and will expire SIX (6 c cause the application to becc	nay a reply be timely filed of thirty (30) days will be considered timely.) MONTHS from the mailing date of this communication me ABANDONED (35 U.S.C. § 133).	on.				
1)⊠	Responsive to communication(s) filed on 04 J	lanuary 2002 .						
2a)[is action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.								
-	ition of Claims							
4)⊠	4)⊠ Claim(s) <u>1-11</u> is/are pending in the application.							
_	4a) Of the above claim(s) is/are withdrawn from consideration.							
•	5) Claim(s) is/are allowed.							
	6)⊠ Claim(s) <u>1-8,10 and 11</u> is/are rejected.							
	7) Claim(s) 9 is/are objected to.							
8) Claim(s) are subject to restriction and/or election requirement. Application Papers								
• •	The specification is objected to by the Examine	r.						
•	The drawing(s) filed on is/are: a)☐ accept		by the Examiner.					
-,_	Applicant may not request that any objection to the							
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.								
If approved, corrected drawings are required in reply to this Office action.								
12) The oath or declaration is objected to by the Examiner.								
Priority under 35 U.S.C. §§ 119 and 120								
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a)⊠ All b)□ Some * c)□ None of:								
	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
*	3. Copies of the certified copies of the prior application from the International Bur See the attached detailed Office action for a list	reau (PCT Rule 17.2	a)).					
14)	14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
15)	 a) The translation of the foreign language pro Acknowledgment is made of a claim for domesting 							
Attachme								
2) No	tice of References Cited (PTO-892) tice of Draftsperson's Patent Drawing Review (PTO-948) ormation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) 🔲 Noti	view Summary (PTO-413) Paper No(s) ce of Informal Patent Application (PTO-152)	. •				

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DETAILED ACTION

Oath/Declaration

1. The oath/declaration filed on 01/04/02 is acceptable.

Information Disclosure Statement

2. If applicant is aware of any relevant prior art, he/she requested to cite it on form PTO-1449 in accordance with the guidelines set forth in M.P.E.P. 609.

Claim Rejections - 35 USC § 102

- 3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:
 - A person shall be entitled to a patent unless -
 - (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- Claims 1, 2, 4-6 are rejected under 35 U.S.C. 102(b) as being anticipated by Nitta (5,798,537).

With regard to claim 1, Nitta discloses a semiconductor device comprising a compound semiconductor substrate 100 having a resistivity less than 1.0×10^8 Ohm-cm at least at surface thereof, a buffer layer 101 formed on the compound semiconductor substrate 100 and having a supper lattice structure; and an active layer 103 formed on the buffer layer 101 and having an active element 204(205) formed therein. (Note lines 26-28, column 5, figs. 1, 2 of Nitta).

With regard to claim 2, Nitta discloses the semiconductor substrate 100 has resistivity less than 0.6×10^8 Ohm-cm. (Note lines 26-28, column 5, figs. 1, 2 of Nitta).

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With regard to claim 4, Nitta discloses an electrode 106 formed on another surface of the compound semiconductor substrate 100. (Note fig. 2 of Nitta).

With regard to claim 5, Nitta discloses the electrode layer 106 is not electrically connected to the semiconductor device. (Note fig. 2 of Nitta).

With regard to claim 6, it is inherent that the electrode layer 106 is connected to one power supply potential of the semiconductor device in order to increase light emitting area. (Note fig. 2 of Nitta).

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3, 10, 11 are rejected under 35 U.S.C. 103(a) as being anticipated by Nitta (5,798,537).

With regard to claim 3, Nitta discloses all the claimed subject matter except for the active layer 103 is formed at a position within 5.0 micrometer from the surface of the compound semiconductor substrate 100. However, it would have been obvious to one of ordinary skill in the art to form the active layer is formed at a position within 5.0 micrometer from the surface of the compound semiconductor substrate in order to maintain the lattice matching between the semiconductors and the sapphire substrate, because such structure is conventional in the art for

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forming blue light emitting device. (Note fig. 2 of Nitta) is cited to support for the well know position.

With regard to claim 10, Nitta discloses all the claimed subject matter except for the compound semiconductor substrate has a resistivity more than 1.0×10^8 Ohm-cm in total. However, it would have been obvious to one of ordinary skill in the art to form the compound semiconductor substrate has a resistivity more than 1.0×10^8 Ohm-cm in total, in order to provide a blue light emitting device capable of adjusting wavelength freely without reducing intensity of the light to be generated, because such structure is conventional in the art for forming blue light emitting device (Note lines 26-28, column 5, figs. 1, 2 of Nitta) is cited to support for the well know position.

With regard to claim 11, Nitta. discloses all the claimed subject matter except for the compound semiconductor substrate comprising a compound semiconductor support substrate having a resistivity more than 1.0×10^8 Ohm-cm and a compound semiconductor having a resistivity less than 1.0×10^8 Ohm-cm. However, it would have been obvious to one of ordinary skill in the art to form the compound semiconductor substrate comprising a compound semiconductor support substrate having a resistivity more than 1.0×10^8 Ohm-cm and a compound semiconductor having a resistivity less than 1.0×10^8 Ohm-cm, in order to provide a blue light emitting device capable of adjusting wavelength freely without reducing intensity of the light to be generated, because such structure is conventional in the art for forming blue light emitting device (Note lines 26-28, column 5, figs. 1, 2 of Nitta) is cited to support for the well know position.

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Claims 7,8 are rejected under 35 U.S.C. 103(a) as being anticipated by Nitta (5,798,537) in view of Applicant's prior art.

With regard to claim 7, Nitta does not disclose a source electrode and a drain electrode formed on the active layer, separated from each other so as to establish a channel region, and a gate electrode formed above the channel region.

However, Applicant's prior art discloses a source electrode 14S and a drain electrode 14D formed on the active layer, separated from each other so as to establish a channel region 13, and a gate electrode 14G formed above the channel region.

Therefore, it would have been obvious to one of ordinary skill in the art to form the Nitta's device having a source electrode and a drain electrode formed on the active layer, separated from each other so as to establish a channel region, and a gate electrode formed above the channel region such as taught by Applicant's prior art in order to provide a blue light emitting device capable of adjusting wavelength freely without reducing intensity of the light to be generated.

With regard to claim 8, Nitta and Applicant's prior art. disclose all the claimed subject matter except for the active layer has 2 dimentional electron Gasses. However, it would have been obvious to one of ordinary skill in the art to form the active layer has 2 dimentional electron Gasses, because such structure is conventional in the art for forming a blue light emitting device.

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Allowable Subject Matter

5. Claim 9 is objected to as being dependent upon a rejected base claim, but would be

allowable if rewritten in independent form including all of the limitations of the base claim and

any intervening claims.

Claims 9 is allowable over the prior art of record, because none of these references

disclose or can be combined to yield the claimed invention such as active layer comprises a

collector layer of a first conducting type; a base layer of a second conducting type formed on the

collector layer; an emitter layer of the first conducting type formed on the base layer.

Conclusion

6. Any inquiry concerning this communication or earlier communication from the examiner

should be directed to Tan Tran whose telephone number is (703) 305-3362. The examiner can

normally be reached on M-F 8:30AM-5PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the

organization where this application or proceeding is assigned are (703) 308-7722 for regular

communications and (703) 308-7724 for after final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is (703) 308-0956.

TT

August 2002

MATHADY J. FLYNIN

SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2800

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